

Electronic Supplementary Material (ESI) for
**Enhancement of diffusion kinetics in porous MoN nanorods based
counter electrode in a dye-sensitized solar cell**

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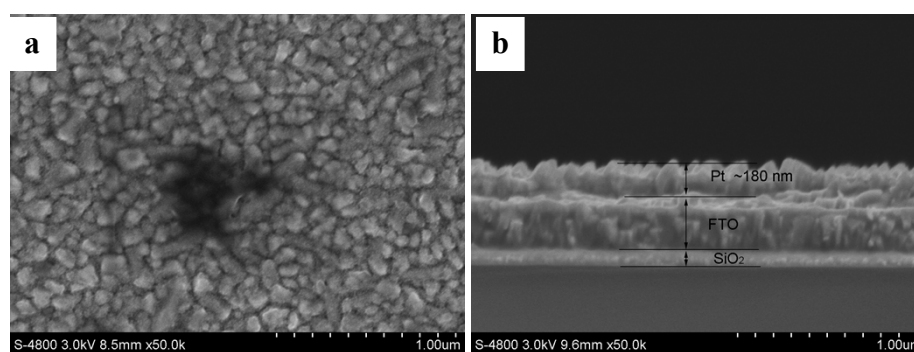


Figure 1S. Surface (a) and cross (b) SEM images of Pt-FTO electrode.

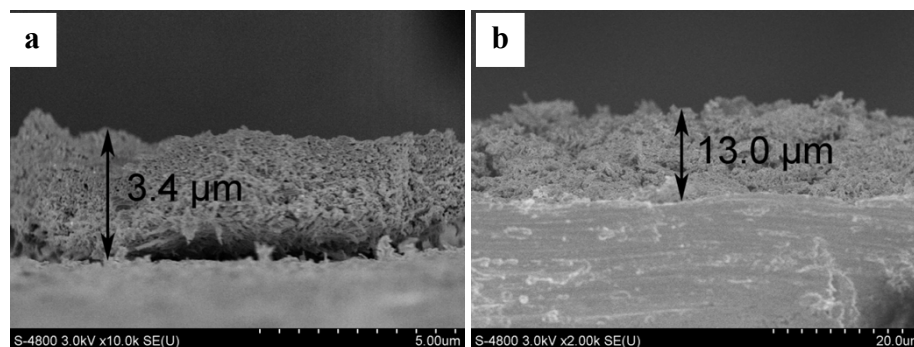


Figure 2S. Cross-section SEM images of MoN NR-Ti electrodes with different film thickness: (a) 3.4 μm and (b) 13.0 μm.

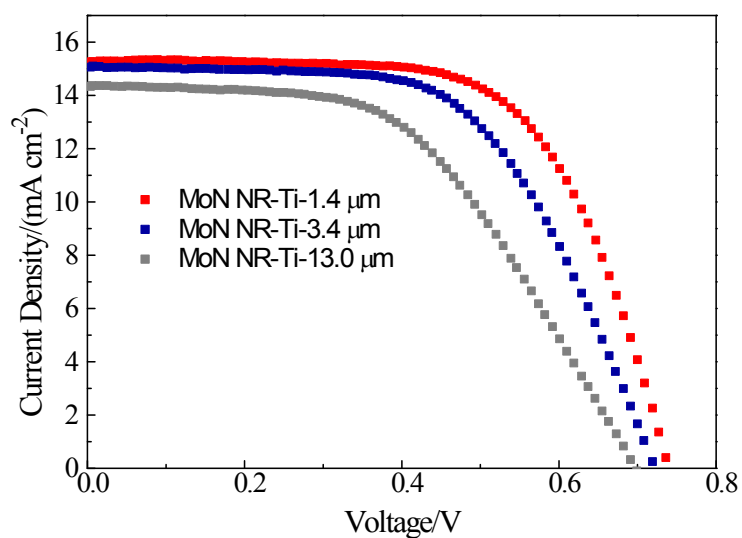


Figure 3 S. J - V curves of DSSCs using MoN NR-Ti counter electrodes with different film thicknesses: 1.4 μm , 3.4 μm and 13.0 μm .

Table S1. The photovoltaic parameters of DSSCs using MoN NR-Ti counter electrodes with different film thicknesses

Sample	V_{oc} (V)	J_{sc} ($\text{mA}\cdot\text{cm}^{-2}$)	FF	η (%)
MoN NR-Ti-1.4 μm	0.740	15.26	0.65	7.29
MoN NR-Ti-3.4 μm	0.725	15.06	0.59	6.43
MoN NR-Ti-13.0 μm	0.695	14.34	0.52	5.20